Fractional-N Frequency Synthesizer for DAB Tuner

Description

The U2733B-C is a monolithic integrated fractional-N frequency synthesizer circuit fabricated in TEMIC's advanced UHF5S technology. Designed for applications in DAB receivers, it controls a VCO to synthesize frequencies in the range of 70 MHz to 500 MHz in a 16 kHz raster; four different reference divide factors can be selected. The lock status of the phase detector is indicated at a special output pin, six switching outputs can be addressed. An internal frequency doubler provides an output signal having twice the frequency of the reference oscillator. All functions of this IC are controlled by I^2C bus.

Electrostatic sensitive device.
Observe precautions for handling.

Features

- Microprocessor-controlled via an I^2C bus
- Four addresses selectable
- Four reference divide factors selectable: 1024, 1120, 1152, 1536 effectively
- Programmable 15-bit counter 1:2048 to 1:32767 effectively
- Tristate phase detector with programmable charge pump
- Superior phase-noise performance
- De-activation of tuning output programmable
- Six switching outputs (open collector)
- Reference frequency doubler (open collector output)
- Lock-status indication (open collector)

Block Diagram

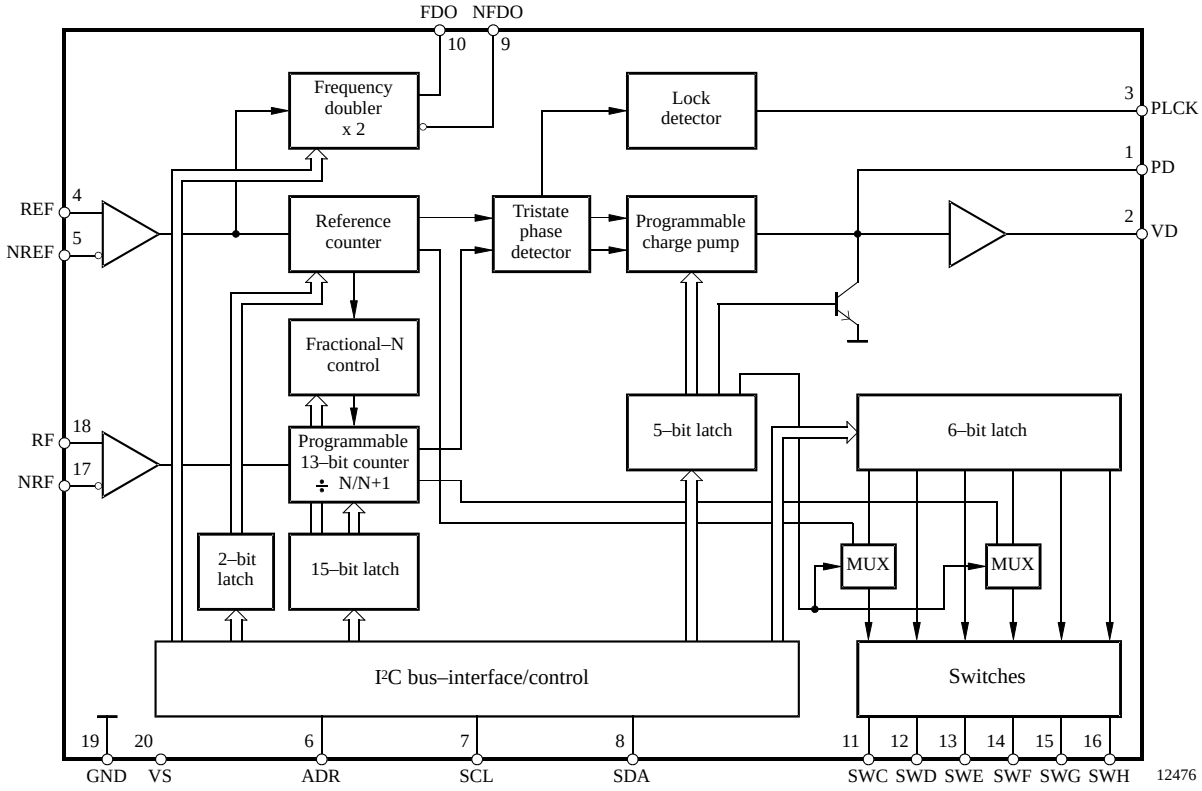


Figure 1. Block diagram

Preliminary Information

Ordering Information

Extended Type Number	Package	Remarks
U2733B-CFS	SSO20	

Pin Description

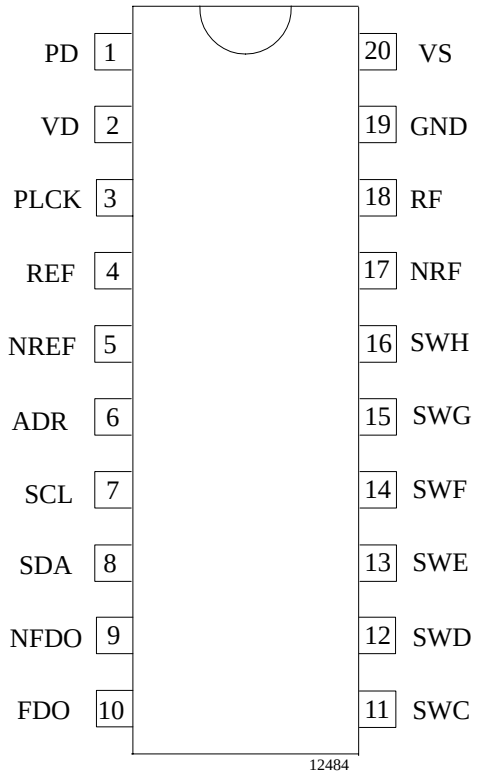


Figure 2. Pinning

Pin	Symbol	Function
1	PD	Tristate charge pump output
2	VD	Active filter output
3	PLCK	Lock-indicating output (open collector)
4	REF	Reference input
5	NREF	Reference input (inverted)
6	ADR	Address selection
7	SCL	Clock (I^2C)
8	SDA	Data (I^2C)
9	NFDO	Frequency-doubler output (inverted, open collector)
10	FDO	Frequency-doubler output (open collector)
11	SWC	Switching output (open collector)
12	SWD	Switching output (open collector)
13	SWE	Switching output (open collector)
14	SWF	Switching output (open collector)
15	SWG	Switching output (open collector)
16	SWH	Switching output (open collector)
17	NRF	RF input (inverted)
18	RF	RF input
19	GND	Ground
20	VS	Supply voltage

Functional Description

The U2733B-C is a low-power fractional-N frequency synthesizer designed for applications in DAB receivers. Its RF operation range reaches from 70 MHz to 500 MHz. The device includes input buffers for reference and RF dividers, a reference divider, a programmable RF divider using fractional-N technique, a tristate phase detector, a programmable charge pump, six switching outputs, a frequency doubler for the reference input signal and a control unit. The control unit has to be accessed by a microcontroller via an I^2C bus. The programming information is stored in a set of internal registers.

The basic difference to the U2753B-C is the use of a special phase-noise shaping technique based on the fractional-N principle which concentrates the phase detector's phase-noise contribution to the spectrum of the controlled VCO at frequency positions where it does not damage the quality of the received DAB signal. In critical locations of the VCO's frequency spectrum, the phase detector's phase-noise contribution is reduced by roughly 12 dB. A special property of the transmission technique used in DAB is that the phase-noise weighting function (which measures the influence of the LO's phase noise on the phase information of the coded signal in a DAB receiver) has zeros, i.e., if phase noise is concentrated in the position of such zeros as discrete lines, the DAB signal is not disturbed as long as these lines do not exceed a certain limit.

For DAB mode I this phase noise weighting function is shown in the following figure:

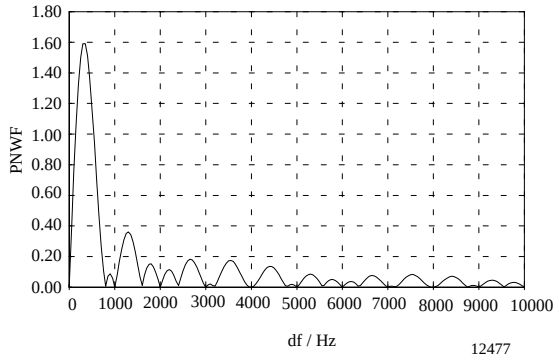


Figure 3. PNWF vs. df/Hz

It is important to realize that this function shows zeros in all distances from the center line which are multiples of the carrier spacing. The technique of concentrating the phase noise in the positions of such zeros is protected by a patent.

In this circuit, the phase detector is operated at a frequency which is four times the desired frequency raster spacing (e.g., 16 kHz in case of DAB) and the well known fractional-N technique is used to synthesize the raster. As a result of this technique, spurious in the VCO's frequency spectrum occur not only in multiples of the phase detector's input comparison frequency (64 kHz) but also in multiples of the raster frequency (16 kHz). As described above for all DAB modes, these spurious are placed in spectral positions where the phase-noise weighting function is zero. Therefore, no measures are necessary to suppress these lines.

Reference Divider

Four different scaling factors, SF_{ref}, of the reference divider can be selected by means of the bits RD1 and RD2 in the I^2C-bus instruction code: 256, 280, 288, and 384. Starting from a reference oscillator frequency of 16.384 MHz/ 17.92 MHz/ 18.432 MHz/ 24.576 MHz, these scaling factors provide a frequency raster of 64 kHz. By changing the division ratio of the main divider from N to N+1 in an appropriate way (fractional-N technique), this frequency raster is interpolated to deliver a frequency spacing of 16 kHz according to the DAB specification. Thus, the reference divide factors 1024, 1120, 1152 and 1536 can be selected effectively. By setting of the I^2C-bus bit T, a test signal representing the divided input signal can be monitored at the switching output SWC.

Main Divider

The main divider consists of a fully programmable 13-bit divider which defines a division ratio N. The applied division ratio is either N or N+1 according to the control of a special control unit. On average, the scaling factors SF = N+k/ 4 can be selected where k = 0, 1, 2, 3. In this way, the VCO frequencies

$$f_{VCO} = 4 \times (N+k/4) \times f_{ref}/(4 \times SF_{ref})$$

can be synthesized starting from a reference frequency, $f_{ref.}$. If we define $SF_{eff} = 4 \times N+k$ and $SF_{ref,\,eff} = 4 \times SF_{ref}$ we end up with

$$f_{VCO} = SF_{eff} \times f_{ref}/SF_{ref,eff},$$

where SF_{eff} is defined by 15 bits. In the following, this circuit is described in terms of SF_{eff} and $SF_{ref,eff}$. SF_{eff} has to be programmed via the I^2C-bus interface. An effective scaling factor from 2048 to 32767 can be selected. By setting the I^2C-bus bit T, a test signal representing the divided input signal can be monitored at the switching output SWF.

When the supply voltage is switched on, both the reference divider and the programmable divider are kept in RESET state till a complete scaling factor is written onto the chip. Changes in the setting of the programmable divider become active when the corresponding I^2C-bus transmission is completed. By an internal synchronization procedure is ensured that such changes do not become active while the charge pump is sourcing or sinking current at its output pin. This behavior enables a smooth tuning of the output frequency without disturbing the controlled VCO's frequency spectrum.

Phase Comparator and Charge Pump

The tristate phase detector causes the charge pump to source or to sink current at the output Pin PD depending on the phase relation of its input signals which are provided by the reference and the main divider respectively. Four different values of this current can be selected by means of the I^2C-bus bits I50 and I100. By using this option, for example, changes of the loop characteristics due to the variation of the VCO gain as a function of the tuning voltage can be reduced. The charge-pump current can be switched off using the I^2C-bus bit TRI. A change in the setting of the charge-pump current becomes active when the corresponding I^2C-bus transmission is completed. As described for the setting of the scaling factor of the programmable divider an internal synchronization procedure ensures that such changes do not become active while the charge pump is sourcing or sinking current at its output pin. This behavior enables a change in the charge-pump current without disturbing the controlled VCO's frequency spectrum.

A high-gain amplifier (output Pin: VD), which is implemented in order to construct a loop filter as shown in the application circuit, can be switched off by means of the I²C-bus bit OS.

An internal lock detector checks if the phase difference of the input signals of the phase detector is smaller than approximately 250 ns in seven subsequent comparisons. If phase lock is detected, the open-collector output Pin PLCK is set HIGH (logical value!). It should be noted that the output current of this pin must be limited by external circuit as it is not limited internally. If the I²C-bus bit TRI is set HIGH the lock detector function is de-activated and the logical value of the PLCK output is undefined.

Switching Outputs

Six switching outputs controlled by the I²C-bus bits SWC, SWD, SWE, SWF, SWG, SWH can be used for any switching task on the front end board. The currents of these outputs are not limited internally. They have to be limited by external circuit.

Frequency Doubler

An internal frequency doubler provides a signal at twice the frequency of the reference signal appearing at the input Pins REF and NREF. If the I²C-bus bit OFD = HIGH, the current of its open-collector outputs FDO and NFDO is doubled. By means of the I²C-bus bit OFD, the frequency-doubler function can be switched off.

As shown in figure 9, the output signal of the frequency doubler can be used in order to construct the LO signal of the IF circuit (U2759B).

I²C-Bus Interface

Via its I²C-bus interface, various functions can be controlled by a microprocessor. These functions are overviewed in the following sections 'I²C bus instruction codes' and 'I²C bus functions'. By means of thePin ADR, four different I²C-bus addresses can be selected as described in the section 'Electrical characteristics'.

I²C-Bus Instruction Codes

Description	MSB							LSB
Address byte	1	1	0	0	0	AS1	AS2	0
Divider byte 1	0	RD1	RD2	X	X	n_{14}	n_{13}	n_{12}
Divider byte 2	X	X	n_{11}	n_{10}	n_9	n_8	n_7	n_6
Divider byte 3	X	X	n_5	n_4	n_3	n_2	n_1	n_0
Control byte 1	1	1	0	OS	T	TRI	I100	I50
Control byte 2	OFD	2IFD	SWC	SWD	SWE	SWF	SWG	SWH
Control byte 3	X	0	0	0	0	0	0	0

I²C-Bus Functions

AS1, AS2 define the I²C-bus address

RD1, RD2 define the effective scaling factor of the reference divider

RD1	RD2	Effective Scaling Factor
0	0	1120
1	0	1152
0	1	1024
1	1	1536

n_i effective scaling factor (SF_{eff}) of the main divider $SF_{eff} = SUM(n_i\ 2^i)$

OS OS = HIGH switches off the tuning output

T for T = HIGH reference signals describing the output frequencies of reference divider and programmable divider are monitored at SWF (programable divider) and SWC (reference divider)

TRI TRI = HIGH switches off the charge pump

I50, I100 define the charge-pump current:

I50	I100	Charge-Pump Current (nominal)/µA
LOW	LOW	50
HIGH	LOW	102
LOW	HIGH	151
HIGH	HIGH	203

OFD OFD = HIGH switches off the frequency doubler

2IFD 2IFD = HIGH doubles the frequency-doubler output current

SWa SWa = HIGH switches on output current

I²C Bus Data Transfer

Format

START – ADR – ACK – <instruction set> – STOP

The <instruction set> consists of a sequence of divider bytes and control bytes each followed by ACK. Divider byte i must be followed by divider byte i+1 (control byte 1 if i = 3) or the instruction set must be finished. Control bytes have to be handled accordingly.

Examples

START – ADR – ACK – DB1 – ACK – DB2 – ACK – DB3 – ACK – CB1 – ACK – CB2 –ACK – CB3 – ACK – STOP

START – ADR – ACK – CB1 – ACK – CB2 – ACK – STOP

However

START – ADR – ACK – DB1 – ACK – CB1 –ACK – STOP is not allowed.

Description

START	start condition
STOP	stop condition
ACK	acknowledge
ADR	address byte
DBi	divider byte i (i = 1, 2, 3)
CBi	control byte i (i = 1, 2, 3)

I²C Bus Timing

The values of the periods shown are specified in the section ‘Electrical Characteristics’. More detailed information can be taken from ‘Application Note 1.0 (I²C -Bus Description)’. Please note: due to the I²C-bus specification, the MSB of a byte is transmitted first, the LSB last.

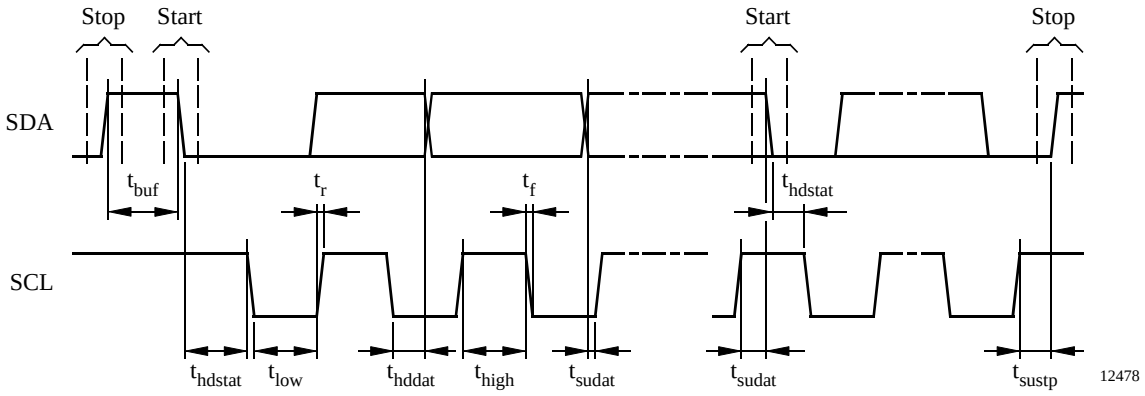


Figure 4. I²C-bus timing diagram

Typical Pulse Diagram

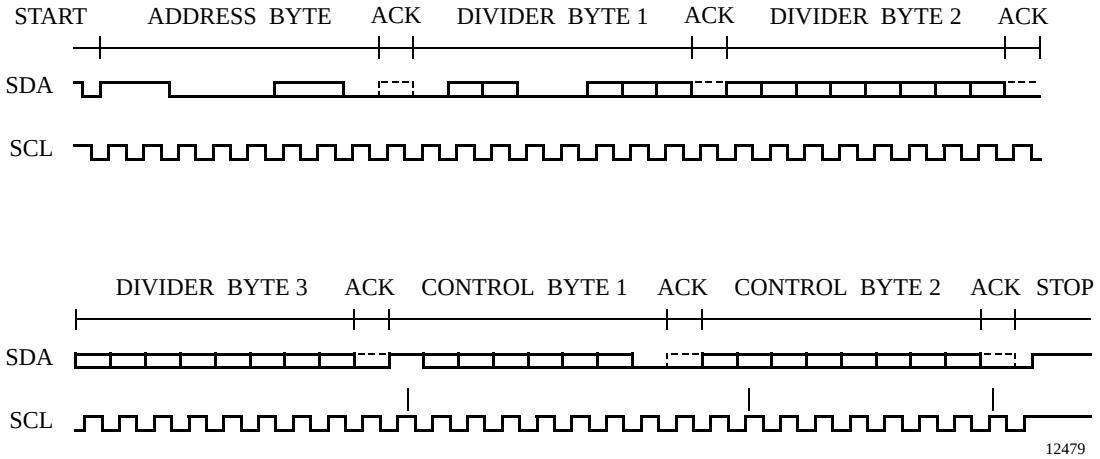


Figure 5. Typical pulse diagram

Absolute Maximum Ratings

Parameters			Symbol	Min.	Typ.	Max.	Unit
Supply voltage			V_S	–0.3		+5.5	V
Junction temperature			T_j			125	°C
Storage temperature			T_{stg}	–40		+125	°C
RF input voltage (AC)	Pins 18 and 17		RF, NRF			1	V_{pp}
Reference input voltage (AC)	Pins 4 and 5		REF, NREF			1	V_{pp}
I^2C-bus input / output voltage		Pins 7 and 8	SCL, SDA	–0.3		V_S	V
SDA output current		Pin 8	SDA			5	mA
Address select voltage		Pin 6	ADR	–0.3		V_S	V
Switch output voltage	open collector		SWa	–0.3		5.5	V
Switch output current	open collector		SWa	4			mA
PLCK output voltage	open collector	Pin 3	PLCK	–0.3		5.5	V
PLCK output current	open collector	Pin 3	PLCK			0.5	mA
Frequency doubler output	open collector	Pins 9 and 10	FDO, NFDO	$V_S - 1$		5.5	V

Operating Range

Parameters	Symbol	Value	Unit
Supply voltage	V_S	4.5 to 5.5	V
Ambient temperature range	T_{amb}	–30 to +85	°C

Thermal Resistance

Parameters		Symbol	Value	Unit
Junction ambient	SSO20	R_{thJA}	140	K/W

Electrical Characteristics

Test conditions: V_S = 5 V, T_{amb} = 25°C, unless otherwise specified

Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Supply current	SW_a = LOW, TRI = LOW, PLCK = LOW, OS = LOW, I50 = HIGH, I100 = HIGH OFD = LOW, 2IFD = LOW	I_s	13.2	16.5	19.8	mA
	SW_a = LOW, TRI = LOW, PLCK = LOW, OS = LOW, I50 = HIGH, I100 = HIGH, OFD = HIGH, 2IFD = LOW	I_{so}		14.6		mA
Effective scaling factor of programmable divider		SF_{eff}	2048		32767	
Effective scaling factor of reference divider	RD1 = LOW, RD2 = LOW RD1 = HIGH,RD2 = LOW RD1 = LOW, RD2 = HIGH RD1 = HIGH, RD2 = HIGH	$SF_{ref,eff}$		1120 1152 1024 1536		
Tuning step	17.920 MHz/ 18.432 MHz/ 16.384 MHz/ 24.576 MHz reference frequency	f_{rast}		16		kHz
RF input, RF, NRF	**Pins 17 and 18**					
Input frequency range	V_S = 4.5 V, T_{amb} = 20°C	f_{rf}	70		500	MHz
Input sensitivity		V_{rfs}		10	20	mV_{rms}
Maximum input signal		V_{rfmax}			300	mV_{rms}
Input impedance	Differential	Z_{rf}		200		Ω
VSWR		$VSWR_{rf}$		2		
REF input, REF, NREF	**Pins 4 and 5**					
Input frequency range	V_S = 4.5 V, T_{amb} = 20°C	f_{ref}	5	17.92 18.432	30	MHz
Input sensitivity		V_{refs}		10		mV_{rms}
Maximum input signal		V_{refmax}			300	mV_{rms}
Input impedance	Single ended	Z_{ref}		2.7 ‖ 2.5		kΩ ‖ pF
Phase detector, PD	**Pin 1**					
Charge pump current	I100 = HIGH, I50 = HIGH	$\pm I_{PD4}$	± 160	± 203	± 240	µA
	I100 = HIGH, I50 = LOW	$\pm I_{PD3}$	± 120	± 151	± 180	µA
	I100 = LOW, I50 = HIGH	$\pm I_{PD2}$	± 80	± 102	± 120	µA
	I100 = LOW, I50 = LOW	$\pm I_{PD1}$	± 40	± 50	± 60	µA
	TRI = HIGH	$\pm I_{PD,tri}$			± 100	nA
Effective phase noise *)	I_{PD} = 203 µA	L_{PD}		–163		dBc/Hz
Lock indication, PLCK						
Leakage current	V_{PLCK} = 5.5 V	$I_{PLCK,L}$			10	µA
Saturation voltage	I_{PLCK} = 0.5 mA	$V_{PLCK,sat}$			0.5	V

*) The phase detector's phase-noise contribution to the VCO's frequency spectrum is referred to the operating frequency of the phase detector divided by 4, according to the fractional-N technique (regularly: 16 kHz).

Electrical Characteristics (continued)

Test conditions: V_S = 5 V, T_{amb} = 25°C, unless otherwise specified

Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Frequency doubler, FDO, NFDO Pins 9 and 10						
Output current	$V_{FDO} = V_S$, $V_{NFDO} = V_S$, 2IFD = LOW	I_{FDOL}, I_{NFDOL}	0.4	0.5	0.6	mA_{pp}
	$V_{FDO} = V_S$, $V_{NFDO} = V_S$, 2IFD = HIGH	I_{FDOH}, I_{NFDOH}	0.8	1.0	1.2	mA_{pp}
Minimum output voltage	V_S = 5 V	V_{FDO}, V_{NFDO}	4			V
Switches, SWa						
Leakage current	V_{SWa} = 5.5 V	$I_{SW,L}$			10	µA
Saturation voltage	I_{SWa} = 4 mA	$V_{SW,sat}$			0.5	V
Address selection, ADR Pin 6						
AS1 = 0, AS2 = 0			0		0.1 V_S	V
AS1 = 0, AS2 = 1				open		
AS1 = 1, AS2 = 0			0.4 V_S		0.6 V_S	V
AS1 = 1, AS2 = 1			0.9 V_S		V_S	V
I^2C bus, SCL, SDA Pins 7 and 8						
Input voltage SCL/SDA	HIGH	V_H	3		5.5	V
	LOW	V_L			1.5	V
Output voltage SDA (open collector)	I_{SDA} = 2 mA, SDA = LOW				0.4	V
SCL clock frequency		f_{SCL}	0.1		100	kHz
Rise time (SCL, SDA)		t_r			1	µs
Fall time (SCL; SDA)		t_f			300	ns
Time before new transmission can start		t_{buf}	4.7			µs
SCL HIGH period		t_{high}	4			µs
SCL LOW period		t_{low}	4.7			µs
Hold time START		t_{hdsta}	4			µs
Setup time START		t_{susta}	4.7			µs
Setup time STOP		t_{sustp}	4.7			µs
Hold time DATA		t_{hddat}	0			µs
Setup time DATA		t_{sudat}	250			ns

Application Circuit

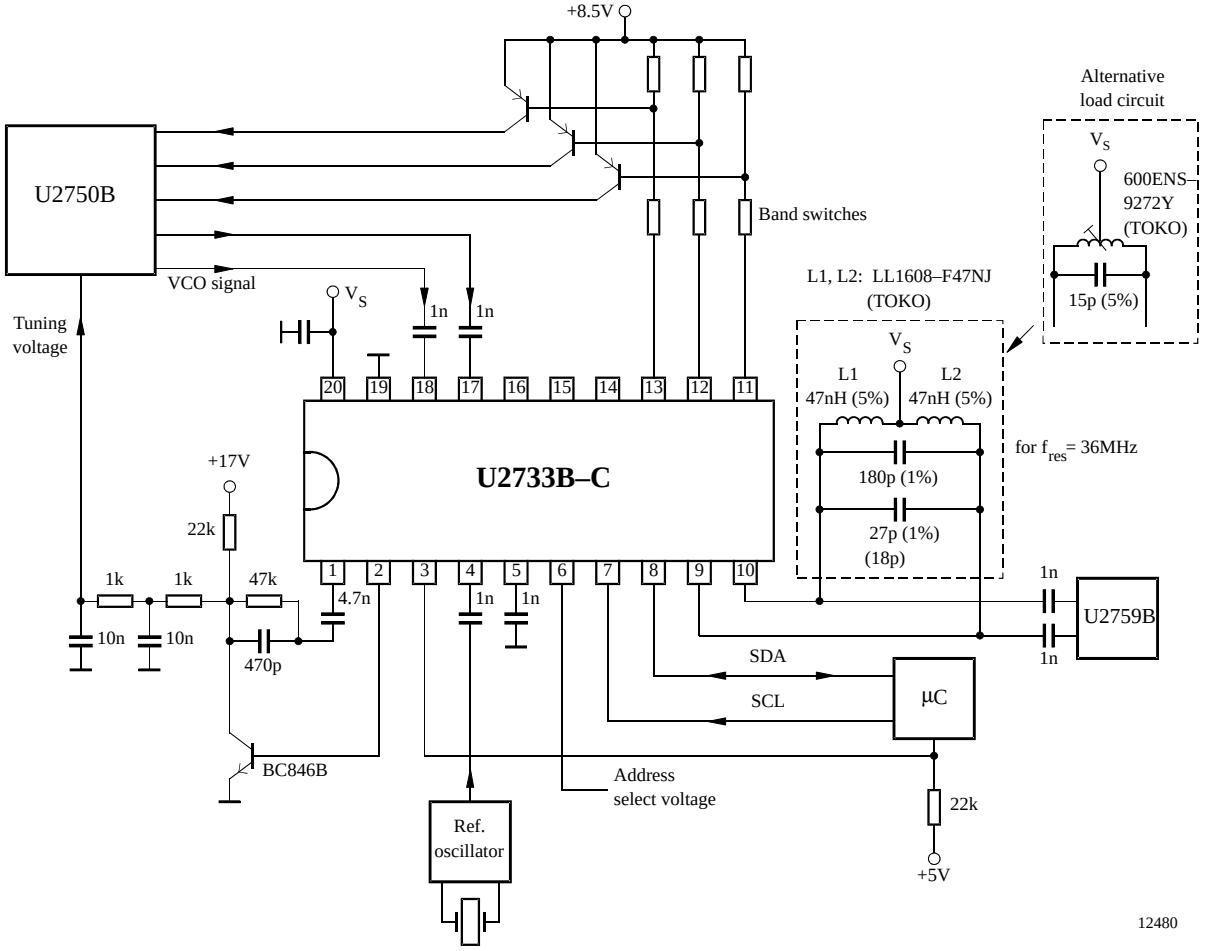


Figure 6. Application circuit

Phase Noise Performance

(Example: SF_{eff} = 16899, $SF_{ref,eff}$ = 1120, f_{ref} = 17.92 MHz, I_{PD} = 200 µA, reference oscillator: MARCONI INSTRUMENTS signal generator 2042, spectrum analysis: HP70000, above shown application circuit, band A oscillator of U2309B)

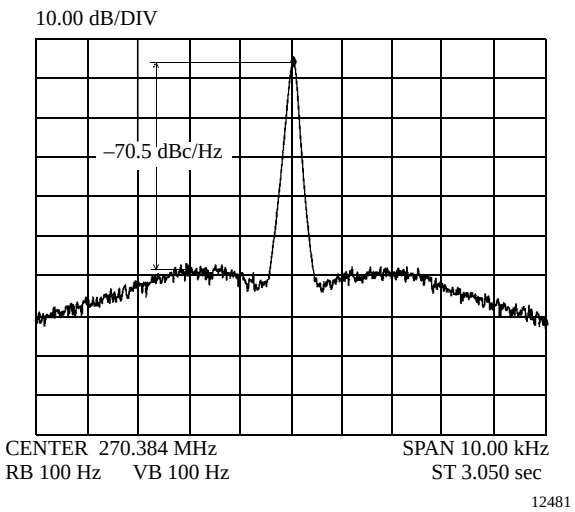


Figure 7.

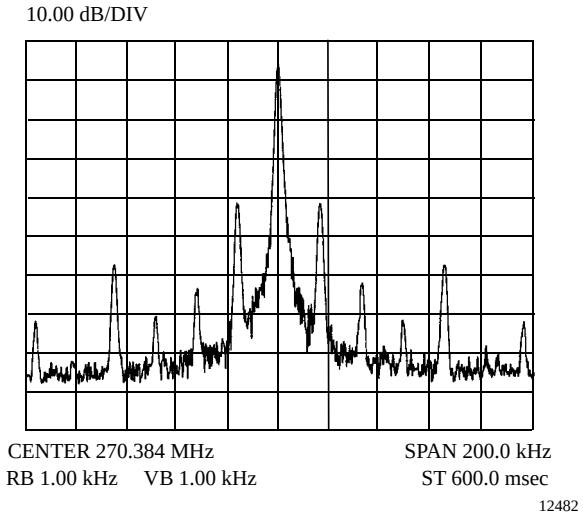


Figure 8.

Integration in TEMIC DAB Receiver Concept

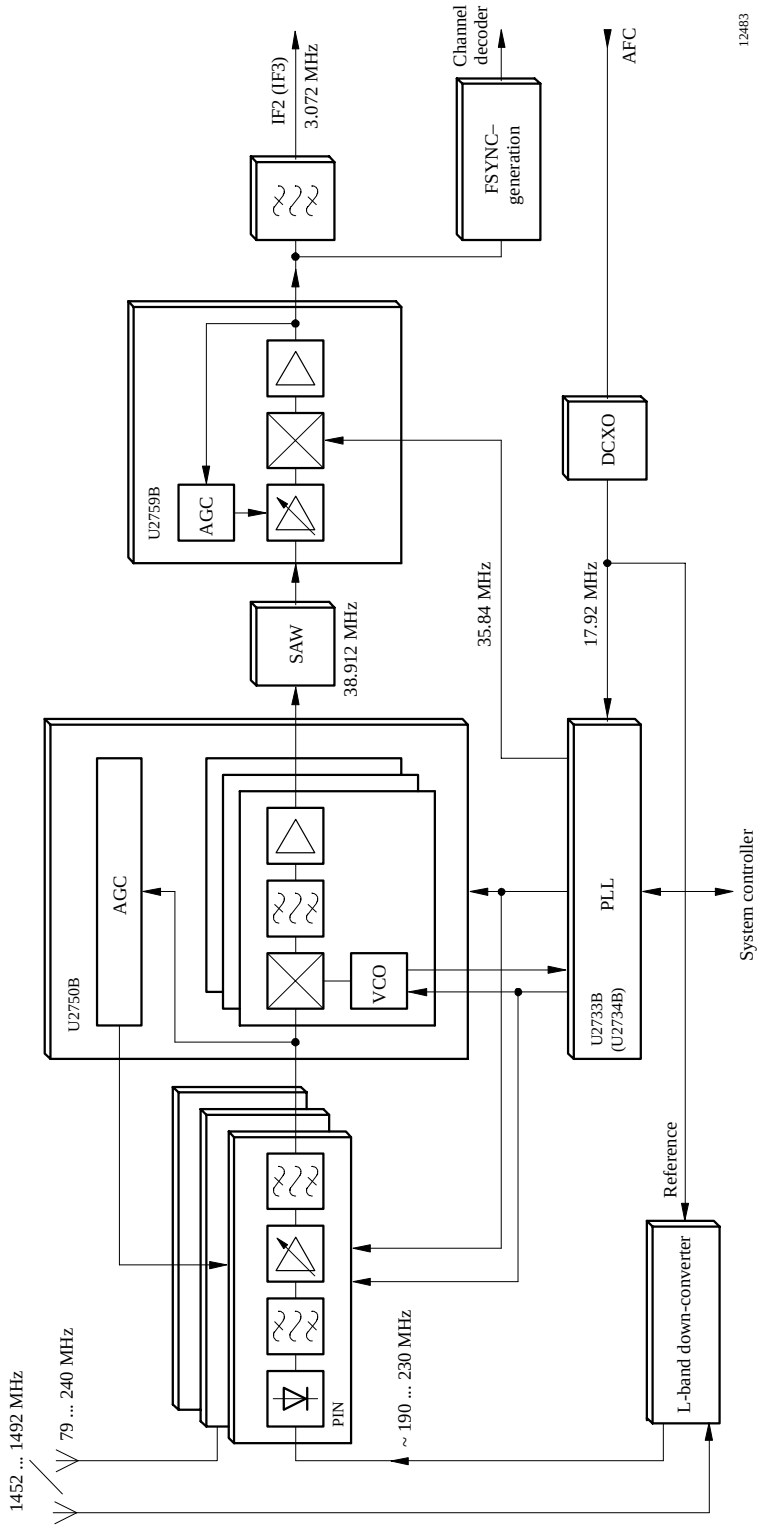
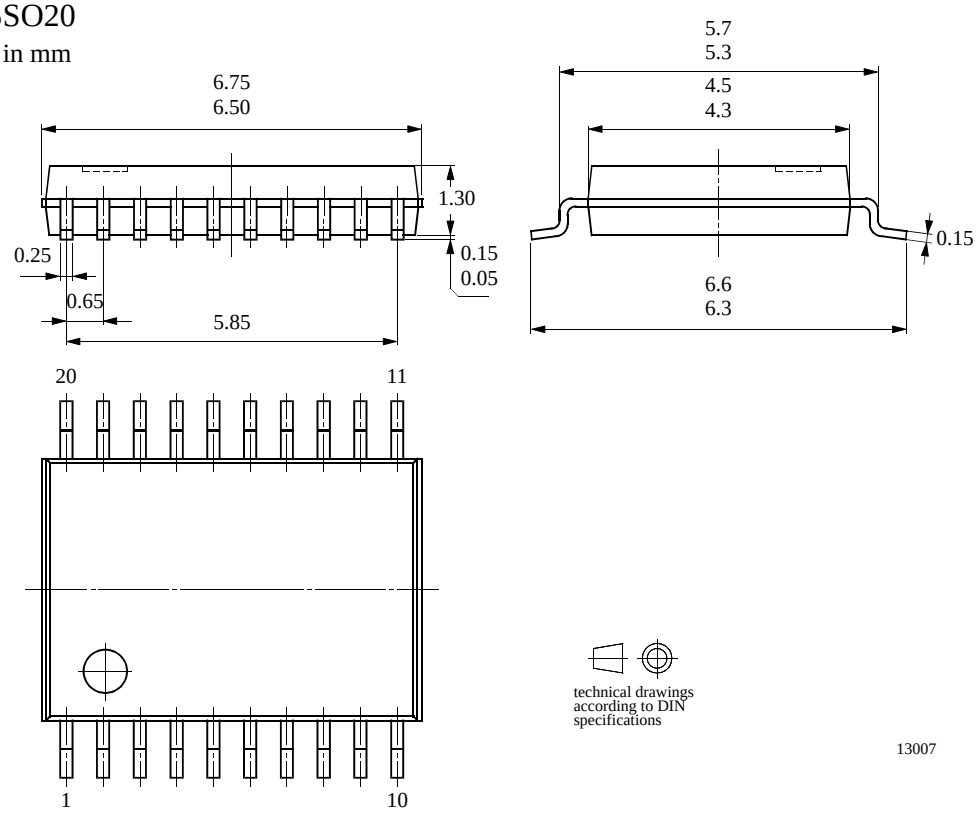


Figure 9. DAB Receiver Frontend

Package Dimensions

Package SSO20
Dimensions in mm



Ozone Depleting Substances Policy Statement

It is the policy of **TEMIC Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.

2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

TEMIC Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively

2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA

3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

TEMIC Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

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